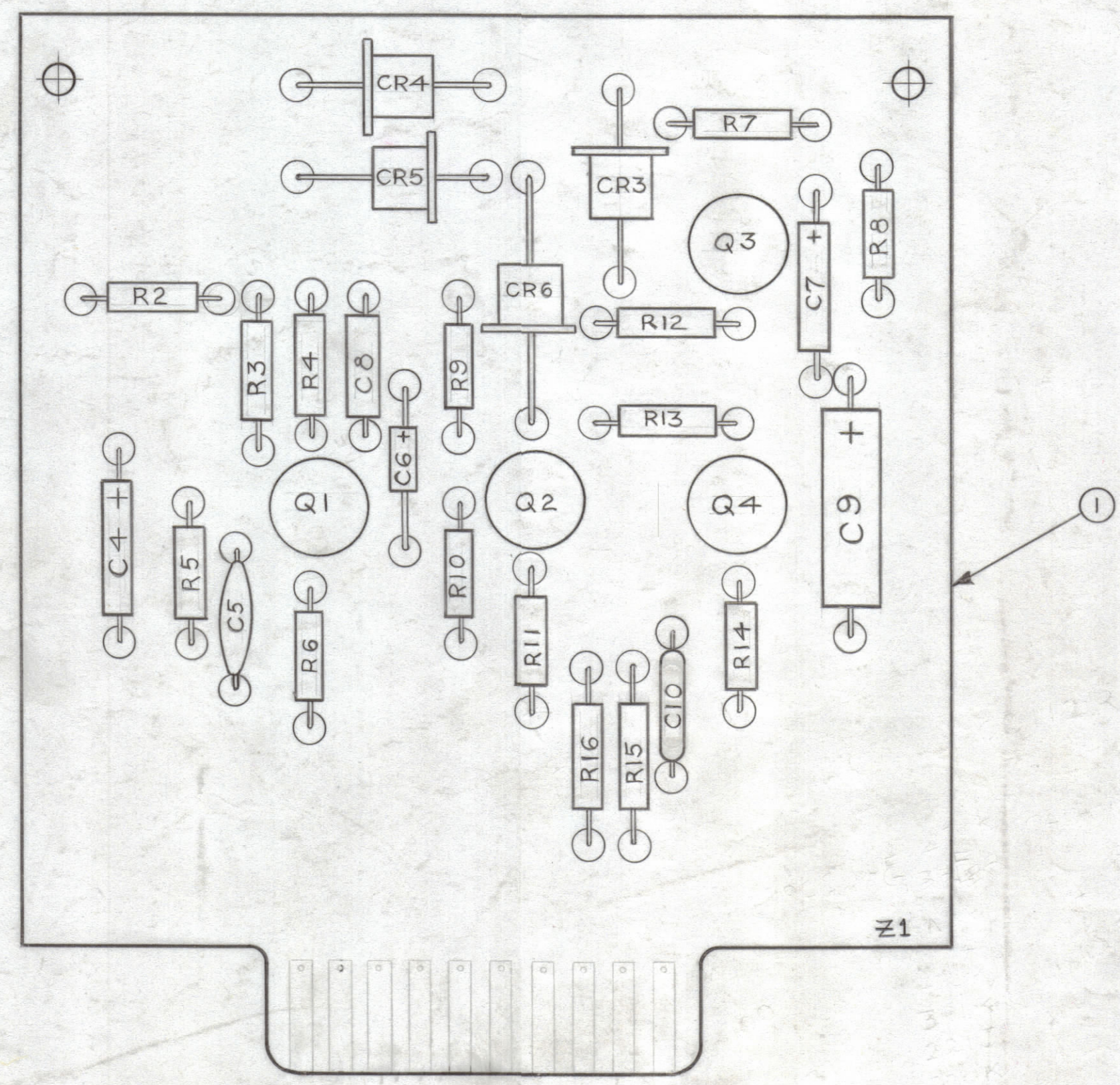


REVISIONS						
ZONE	SYM	DESCRIPTION	DATE	E.M.N. NO.	DRAFT	CHKD
	X	EXPERIMENTAL RELEASE	7-23-64		NP	
E2	X1	ITEMS (25) & (26) ADDED TO BUILD-UP	8-18-64	X1	Phan	
+	Ø	ORIGINAL RELEASE FOR PRODUCTION	10-14-64	Ø	SB	
D2	A	IT. 15 WAS CE107-1, IT. 16 WAS CE107-3, IT. 17 WAS CE107-6	2-3-65	13355	SB	
	B	IT. 19 WAS CC112R474; ITS. 25 & 26 WERE "IN..."	2-25-65	13486	SB	
	C	IT 3 WAS 124K. * NOTE ADDED	7/13/65	14780	H.V.	
	D	IT. 27 PX829-1 ADDED	7/20/65	15051	H.V.	
	E	ITEM 3 WAS RC20GF913J	2-16-66	15804	H.V.	
	F	IN NOTE 120,000Ω WAS 91,000Ω, ADDED-Z1	8/25/66	16714	CE D	



QTY.	UNIT	MODEL USED ON	ASS'Y. NO.	DESCRIPTION	SYMBOL
4	27	PX829-1		PAD, TSTR	
1	26	1N91		DIODE	CR6
3	25	1N599		DIODE	CR3,4,5
X	24	BS100		SOLDER	
1	23	2N1131		TRANSISTOR	Q4
2	22	2N697		TRANSISTOR	
1	21	2N2108		TRANSISTOR	Q3
1	20	CC100-36		CAPACITOR, FIXED, CERAMIC	C5
1	19	CC112R474M		CERAMIC	C10
1	18	CM15B471J		MICA	C8
2	17	CE105-25-50		ELECTROLYTIC	
1	16	CE105-6-15		ELECTROLYTIC	C6
1	15	CE105-50-50		CAPACITOR, FIXED, ELECTROLYTIC	C9
1	14	RC20GF473K		RESISTOR, FIXED, COMPOSITION	R5
1	13	332K			R2
1	12	154K			R3
1	11	683K			R16
1	10	682K			R8
1	9	472K			R4
1	8	391K			R11
1	7	221J			R13
1	6	220K			R15
1	5	183K			R10
2	4	152K			R7,6
1	3	124J			R9
2	2	RC20GF102J		RESISTOR, FIXED, COMPOSITION	R12, 14
1	1	PC 113		PRINTED CIRCUIT BOARD	

* NOTE - VALUE OF R9 IS 120,000Ω NOMINAL. EXACT VALUE MUST BE FACTORY SELECTED DURING TEST PROCEDURE.

FUNGUS PROOFING PER TMC SPECIFICATION S-113

NOTES

1	AZ102	
QTY./UNIT	MODEL USED ON	ASS'Y. NO.
SCALE 2:1	CODE A	

UNLESS OTHERWISE SPECIFIED DIMENSIONS ARE IN INCHES AND INCLUDE CHEMICALLY APPLIED OR PLATED FINISHES

DRAWN	DATE	FINAL APPROVAL	DATE
CHECKED	DATE		
ELECT. DES.	DATE	A3699	
MECH. DES.	DATE	F	

A3699